2SC6043

Bipolar Transistor 50V, 2A, Low VCE(sat) NPN Single MP



Applications

• Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of MBIT process
- High current capacitance

- Low collector to emitter saturation voltage
- High-speed switching

Specifications

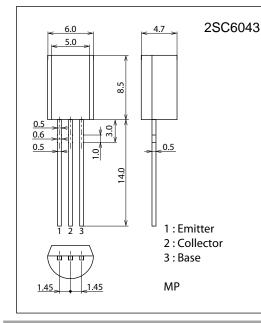
Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	VCBO		80	V
Collector to Emitter Voltage	VCES		80	V
Collector to Emitter Voltage	VCEO		50	V
Emitter to Base Voltage	VEBO		6	V
Collector Current	IC		2	А
Collector Current (Pulse)	ICP		4	А
Base Current	IB		400	mA
Collector Dissipation	PC		1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7520-002

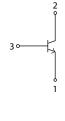


Product & Package Information

- Package
- : MP : SC-51, TO-92(1-WATT), TO-226AE
- JEITA, JEDEC
- Minimum Packing Quantity : 1,000 pcs./box



Electrical Connection

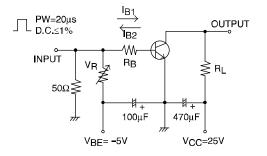


Semiconductor Components Industries, LLC, 2013 November, 2013

Electrical Characteristics at $Ta = 25^{\circ}C$

Deservator				Ratings			
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0A			1	μΑ	
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			1	μΑ	
	hFE1	V _{CE} =2V, I _C =100mA	200		560		
DC Current Gain	hFE2	V _{CE} =2V, I _C =1.5A	40				
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =300mA		420		MHz	
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		9		pF	
Collector to Emitter Saturation Voltage	V _{CE} (sat)	I _C =1A, I _B =50mA		150	300	mV	
Base to Emitter Saturation Voltage	V _{BE} (sat)	I _C =1A, I _B =50mA		0.94	1.2	V	
Collector to Base Breakdown Voltage	V(BR)CBO	I _C =10μΑ, I _E =0Α	80			V	
Collector to Emitter Breakdown Voltage	V(BR)CES	I _C =100μA, R _{BE} =0Ω	80			V	
Collector to Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	50			V	
Emitter to Base Breakdown Voltage	V(BR)EBO	I _E =10μΑ, I _C =0Α	6			V	
Turn-ON Time	ton			35		ns	
Storage Time	tstg	See specified Test Circuit		330		ns	
Fall Time	tf			40		ns	

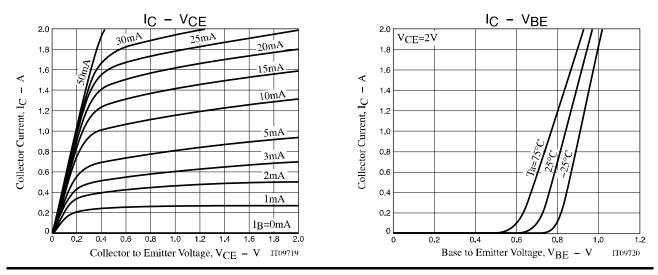
Switching Time Test Circuit

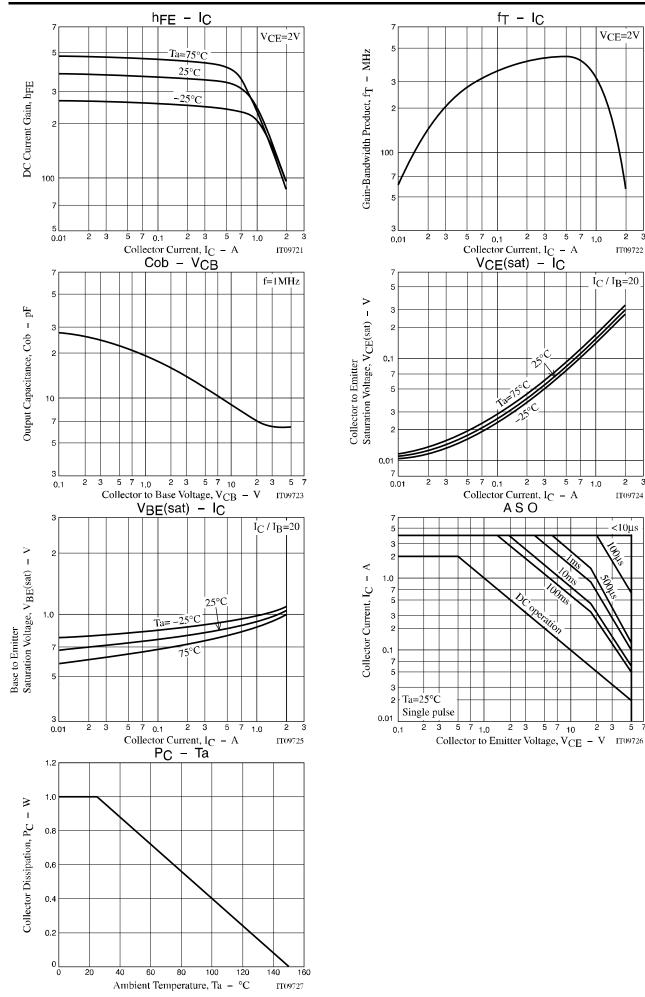


 $I_{C}=10I_{B1}=-10I_{B2}=700$ mA

Ordering Information

Device	Device Package Shipping		Memo	
2SC6043	10	500pcs./bag		
2SC6043-AE	MP	1,000pcs./box	Pb Eree	





V_{CE}=2V

2 3

 $I_C / I_B = 20$

2 3

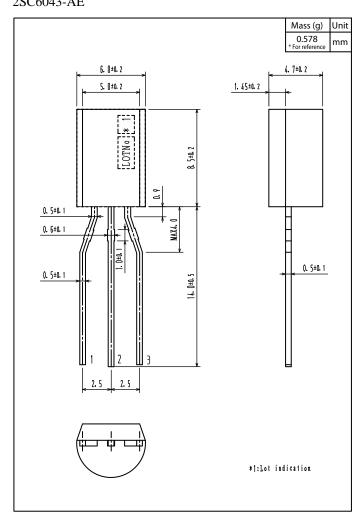
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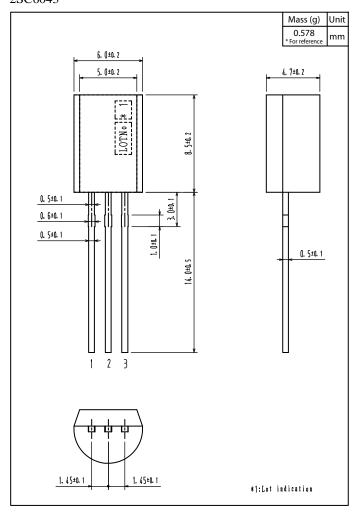
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Outline Drawing 2SC6043-AE



Outline Drawing 2SC6043



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